



# AMP3090P-1 SOLID STATE HIGH POWER PULSE AMPLIFIER

## FEATURES

Ruggedized, compact Class AB high power pulse SSPA  
 Suitable for S-Band, high power Radar applications  
 Internal capacitive bank provides low output droop over extended pulse widths.

## ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification			Notes
Operating Frequency	2.9 - 3.1 GHz			
Peak Pulse Output Power	400 Watt Min			Peak Pulse
Peak Power Gain	56 dB Min			
Input Pulse Characteristics	<b>Pulse Width(tp)</b>	<b>Duty Cycle(δ)</b>	<b>PRF</b>	Nominal Values
	150 μS	20 %	10 KHz	
Pulse Rise / Fall Time	100 nS Max			
Pulse Droop	0.5 dB Max			
Input Return Loss	-12 dB Max			Relative to 50 Ohm
Harmonics	-30 dBc Max			
Spurious	-60 dBc Max			Non-harmonics or Gaussian
Operating Voltage	50 VDC Nom			
Current Consumption	<6 Amp Avg Typ			At 20% duty
Input Power Protection	+3 dBm Max			<10 Sec without damage
Load VSWR Protection	∞ : 1			Internal output circulator

## ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Note
Operating Case Temperature	-20 to +70°C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

## MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	180 x 120 x 32 mm	Excluding connectors
Weight	4 Kg. Typ	
RF Connectors In/Out	SMA female / Type N female	
DC Power / Interface Connector	7-Pin Hybrid D-Sub	
Cooling	External Heatsink	Forced air required

## D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	Option	Pulse Trigger
2	N/C	
3	CURRENT SENSOR	I <sub>b</sub> @50mV/100mA Typ
4	TEMP SENSOR	V <sub>T</sub> @10mV/°C + 500mV Typ
5	SHUTDOWN	+5VDC or OPEN HPA ON / 0V or SHORT HPA OFF
A1	VDD	50VDC
A2	GND	Ground

## OUTLINE DRAWING

